

M37450E8-XXXSP/FP**M37450E8SS/FS**

PROM VERSION of M37450M8-XXXSP/FP

DESCRIPTION

The M37450E8-XXXSP is a single-chip microcomputer designed with CMOS silicon gate technology. It is housed in a 64-pin shrink plastic molded DIP. The features of this chip are similar to those of the M37450M8-XXXSP except that this chip has a 16384-byte PROM built-in. This single-chip microcomputer is useful for office automation appliances and consumer appliance controllers.

In addition to its simple instruction sets, the PROM, RAM and I/O addresses are placed on the same memory map to enable easy programming. Since general purpose PROM writes can be used for small quantity production runs. It also has a unique feature that enables it to be used as a slave microcomputer.

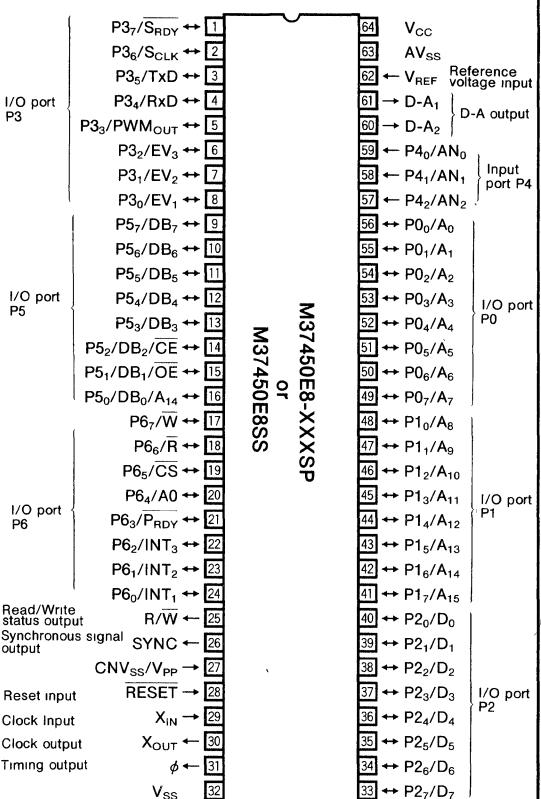
The M37450E8SS and the M37450E8FS are the window type (M37450E8FS is housed in a 80-pin ceramic QFN package). The differences between the M37450E8-XXXSP and the M37450E8-XXXFP, and between the M37450E8SS and the M37450E8FS are the package outline and the power dissipation ability (absolute maximum ratings).

FEATURES

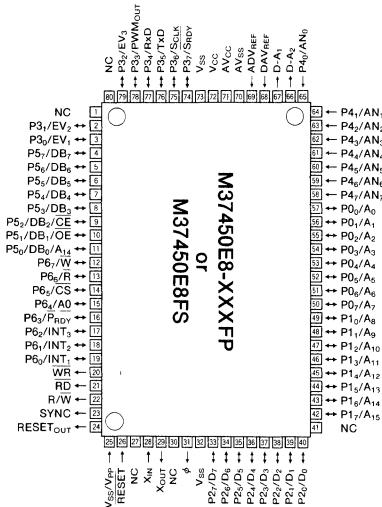
- Number of basic instructions 71
 69 MELPS 740 basic instructions + 2 multiply/divide instructions
- Memory size EPROM 16384 bytes
 RAM 384 bytes
- Instruction execution time
 (minimum instructions at 10 MHz frequency) $0.8\mu s$
- Single power supply 5V $\pm 5\%$
- Power dissipation normal operation mode
 (at 10 MHz frequency) 30mW
- Subroutine nesting 96 levels max.
- Interrupt 15 events
- Master CPU bus interface 1 byte
- 16-bit timer 3
- 8-bit timer (Serial I/O use) 1
- Serial I/O (UART or clock synchronous) 1
- A-D converter (8-bit resolution) 3 channels (DIP)
 8 channels (QFP)
- D-A converter (8-bit resolution) 2 channels
- PWM output (8-bit or 16-bit) 1
- Programmable I/O ports
 (Ports P0, P1, P2, P3, P5, P6) 48
- Input port (Port P4) 3 (DIP), 8 (QFP)
- Output ports (Ports D-A₁, D-A₂) 2
- EPROM (equivalent to the M5L27256)
 program voltage 12.5V

APPLICATION

Slave controller for PPCs, facsimiles, and page printers
HDD, optical disk, inverter, and industrial motor controllers
Industrial robots and machines

PIN CONFIGURATION (TOP VIEW)

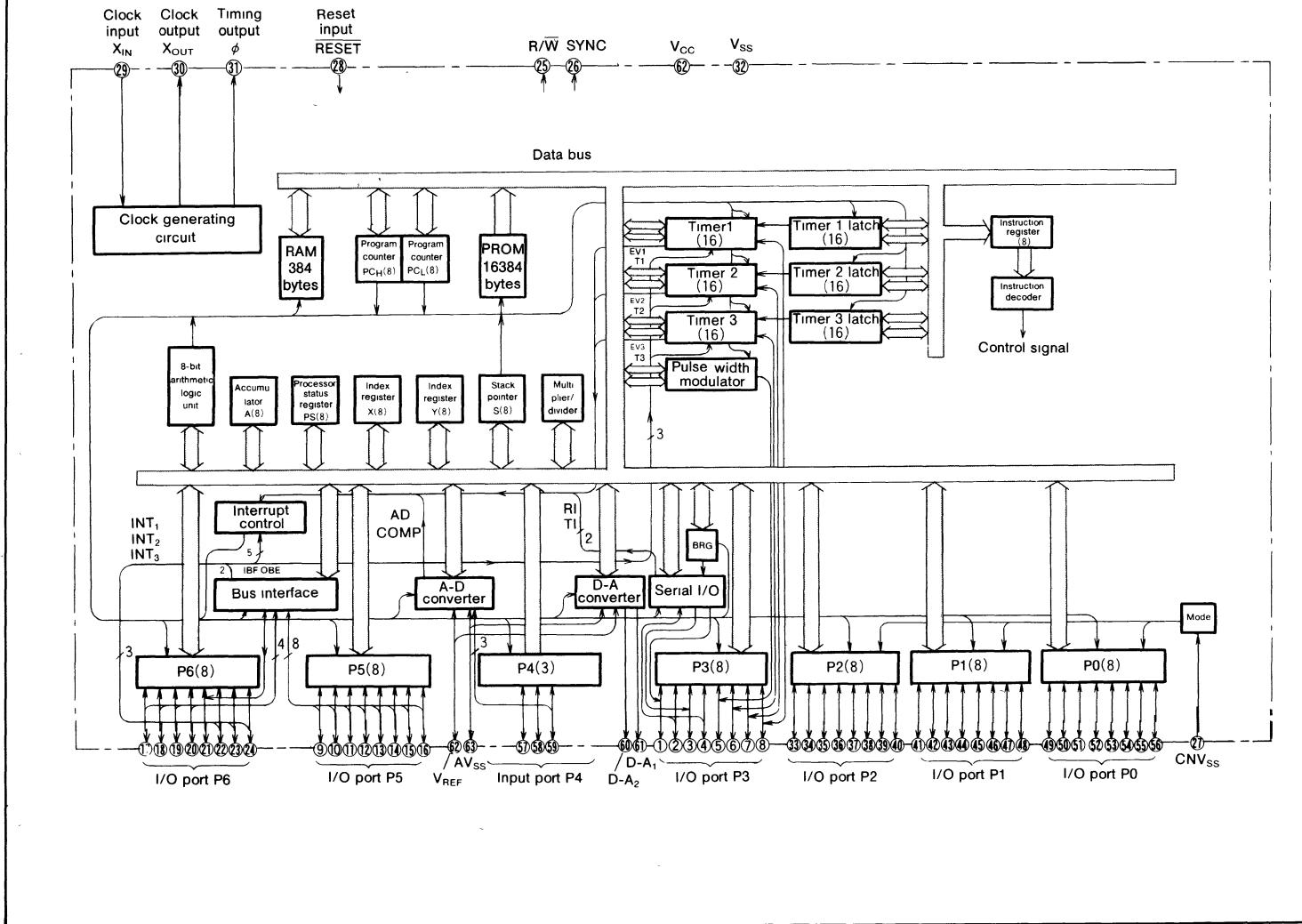
Outline 64P4B(OTP)
64S1B(Window)



Outline 80P6(OTP)
80D0(Window)

NC : No connection

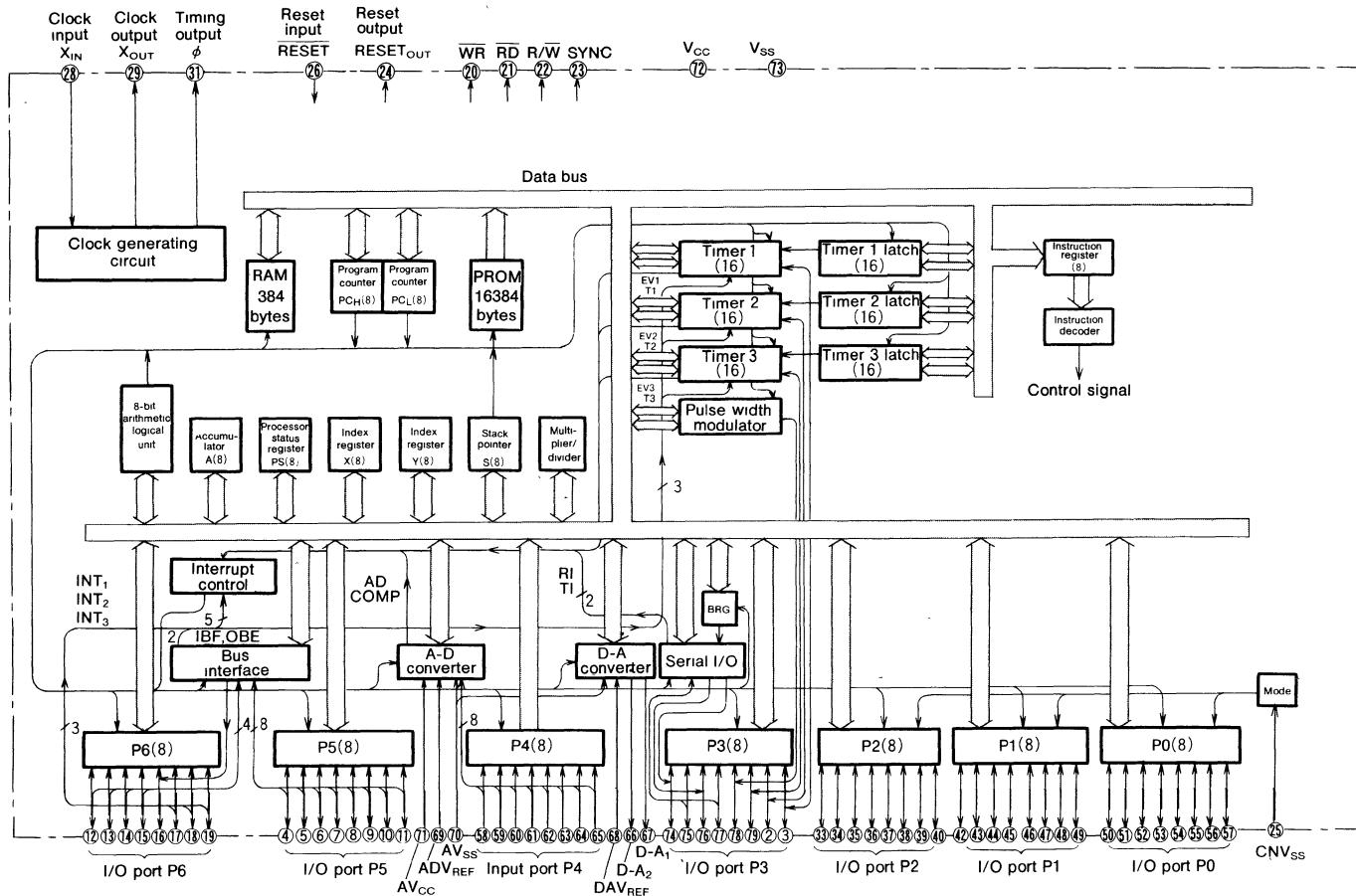
M37450E8-XXXSP, M37450E8SS BLOCK DIAGRAM



PROM VERSION of M37450M8-XXXSP/FP

MITSUBISHI MICROCOMPUTERS
M37450E8-XXXSP/FP
M37450E8SS/FS

M37450E8-XXXFP, M37450E8FS BLOCK DIAGRAM



PROM VERSION of M37450M8-XXXSP/FP
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PROM VERSION of M37450M8-XXXSP/FP

FUNCTIONS OF M37450E8-XXXSP/FP, M37450E8SS/FS

Parameter		Functions	
Number of basic instructions		71(69 MELPS 740 basic instructions+2)	
Instruction execution time		0.8μs (minimum instructions, at 10MHz frequency)	
Clock frequency		10MHz (max)	
Memory size	PROM	16384 bytes	
	RAM	384 bytes	
Input/Output port	P0-P3, P5, P6	I/O	8-bit×6
	P4	Input	3-bit×1 (8-bit×1 for 80-pin model)
	D-A	Output	2-bit×1
Serial I/O		UART or clock synchronous	
Timers		16-bit timer×3, 8-bit timer (Serial I/O baud rate generator)×1	
A-D converter		8-bit×3 channels (8 channels for 80-pin model)	
D-A converter		8-bit×2 channels	
Pulse width modulator		8-bit or 16-bit×1	
Data bus buffer		1-byte input and output each	
Subroutine nesting		96-levels	
Interrupt		6 external interrupts, 8 internal interrupts One software interrupt	
Clock generating circuit		Built-in (ceramic or quartz crystal oscillator)	
Supply voltage		5V±5%	
Power dissipation		30mW (at 10MHz frequency)	
Input/Output characters	Input/Output voltage	5V	
	Output current	±5mA (max.)	
Memory expansion		Possible	
Operating temperature range		−10 to 70°C	
Device structure		CMOS silicon gate	
Package	M37450E8-XXXSP	64-pin shrink plastic molded DIP	
	M37450E8-XXXFP	80-pin plastic molded QFP	
	M37450E8SS	64-pin shrink ceramic DIP	
	M37450E8FS	80-pin ceramic QFN	

PIN DESCRIPTION (normal mode)

Pin	Name	Input/ Output	Functions
V _{CC} , V _{SS}	Supply voltage		Power supply inputs 5V±5% to V _{CC} , and 0V to V _{SS}
CNV _{SS} /V _{PP}	CNV _{SS}		Controls the processor mode of the chip Normally connected to V _{SS} or V _{CC}
<u>RESET</u>	Reset input	Input	To enter the reset state, the reset input pin must be kept at a "L" for more than 8 clock cycles (under normal V _{CC} conditions) If more time is needed for the crystal oscillator to stabilize, this "L" condition should be maintained for the required time
X _{IN}	Clock input	Input	This chip has an internal clock generating circuit To control generating frequency, an external ceramic or a quartz crystal oscillator is connected between the X _{IN} and X _{OUT} pins If an external clock is used, the clock source should be connected to the X _{IN} pin and the X _{OUT} pin should be left open.
X _{OUT}	Clock output	Output	
φ	Timing output	Output	Outputs signal consisting of oscillating frequency divided by four
SYNC	Synchronous signal output	Output	This signal is output "H" during operation code fetch and is used to control single stepping of programs.
R/W	Read/Write status output	Output	This signal determines the direction of the data bus It is "H" during read and "L" during write
P0 ₀ -P0 ₇	I/O port P0	I/O	Port P0 is an 8-bit I/O port with directional registers allowing each I/O bit to be individually programmed as input or output. The output structure is CMOS output. The low-order bits of the address are output except in single-chip mode.
P1 ₀ -P1 ₇	I/O port P1	I/O	Port P1 is an 8-bit I/O port and has basically the same functions as port P0 The high-order bits of the address are output except in single-chip mode
P2 ₀ -P2 ₇	I/O port P2	I/O	Port P2 is an 8-bit I/O port and has basically the same functions as port P0 Used as data bus except in single-chip mode.
P3 ₀ -P3 ₇	I/O port P3	I/O	Port P3 is an 8-bit I/O port and has basically the same functions as port P0 Serial I/O, PWM output, or event I/O function can be selected with a program.
P4 ₀ -P4 ₂ (P4 ₀ -P4 ₇)	Input port P4	Input	Analog input pin for the A-D converter The 64-pin model has three pins and the 80-pin model has eight pins. They may also be used as digital input pins
P5 ₀ -P5 ₇	I/O port P5	I/O	Port P5 is an 8-bit I/O port and has basically the same functions as port P0 This port functions as an 8-bit data bus for the master CPU when slave mode is selected with a program.
P6 ₀ -P6 ₇	I/O port P6	I/O	Port P6 is an 8-bit I/O port and has basically the same function as port P0 Pins P6 ₃ to P6 ₇ change to a control bus for the master CPU when slave mode is selected with a program Pins P6 ₀ to P6 ₂ may be programmed as external interrupt input pins
D-A ₁ , D-A ₂	D-A output	Output	Analog signal from D-A converter is output
V _{REF}	Reference voltage input	Input	Reference voltage input pin for A-D and D-A converter This pin is for 64-pin model only
ADV _{REF}	A-D reference voltage input	Input	Reference voltage input pin for A-D converter This pin is for 80-pin model only
DAV _{REF}	D-A reference voltage input	Input	Reference voltage input pin for D-A converter This pin is for 80-pin model only
AV _{SS}	Analog power supply		Ground level input pin for A-D and D-A converter Same voltage as V _{SS} is applied.
AV _{CC}	Analog power supply		Power supply input pin for A-D converter. This pin is for 80-pin model only Same voltage as V _{CC} is applied. In the case of the 64-pin model, AV _{CC} is connected to V _{CC} internally.
<u>RD</u>	Read signal output	Output	Control signal output as active "L" when valid data is read from data bus This pin is for 80-pin model only.
<u>WR</u>	Write signal output	Output	Control signal output as active "L" when writing data from data bus to external component This pin is for 80-pin model only
RESET _{OUT}	Reset output	Output	Control signal output as active "H" during reset It is used as a reset output signal for peripheral components This pin is for 80-pin model only

MITSUBISHI MICROCOMPUTERS
M37450E8-XXXSP/FP
M37450E8SS/FS

PROM VERSION of M37450M8-XXXSP/FP

PIN DESCRIPTION (EPROM mode)

Pin	Name	Input/ Output	Functions
V _{CC} , V _{SS}	Supply voltage		Power supply inputs 5V or 6V to V _{CC} , and 0V to V _{SS}
CNV _{SS} /V _{PP}	V _{PP}	Input	Connect to V _{PP} when programming or verifying
RESET	Reset input	Input	Connect to V _{SS} .
X _{IN}	Clock input	Input	Connect a ceramic or a quartz crystal oscillator between X _{IN} and X _{OUT} for clock oscillation
X _{OUT}	Clock output	Output	
φ	Timing output	Output	For timing output
SYNC	Synchronous signal output	Output	Kept to open ("L" signal is output)
R/WR	Read/Write status output	Output	Kept to open ("H" signal is output).
P0 ₀ -P0 ₇	I/O port P0	Input	P0 works as the lower 8-bit address input
P1 ₀ -P1 ₇	I/O port P1	Input	P1 ₀ to P1 ₅ works as the higher 6-bit address input. P1 ₆ and P1 ₇ connect to V _{CC} or V _{SS}
P2 ₀ -P2 ₇	I/O port P2	I/O	P2 works as an 8-bit data bus.
P3 ₀ -P3 ₇	I/O port P3	Input	Connect to V _{SS} .
P4 ₀ -P4 ₂ (P4 ₀ -P4 ₇)	Input port P4	Input	Connect to V _{SS} (The 80-pin model has eight pins P4 ₀ to P4 ₇).
P5 ₀ -P5 ₇	I/O port P5	Input	P5 ₀ , P5 ₁ and P5 ₂ work as A ₁₄ , OE, and CE inputs respectively. Connect P5 ₃ and P5 ₄ to V _{CC} and P5 ₅ to P5 ₇ to V _{SS} .
P6 ₀ -P6 ₇	I/O port P6	Input	Connect to V _{SS}
D-A ₁ , D-A ₂	D-A output	Output	Kept to open.
V _{REF}	Reference voltage input	Input	Connect to V _{SS}
ADV _{REF}	A-D reference voltage input	Input	Connect to V _{SS}
DAV _{REF}	D-A reference voltage input	Input	Connect to V _{SS} .
AV _{SS}	Analog power	Input	Connect to V _{SS} .
AV _{CC}	Analog power	Input	Connect to V _{CC} or V _{SS}
RD	Read signal output	Output	Kept to open ("H" signal is output)
WR	Write signal output	Output	Kept to open ("H" signal is output)
RESET _{OUT}	Reset output	Output	Kept to open ("H" signal is output)

PROM VERSION of M37450M8-XXXSP/FP**EPROM MODE**

The M37450E8-XXXSP/FP, M37450E8SS/FS features an EPROM mode in addition to its normal modes. When the RESET signal level is low ("L") and CNV_{SS}/V_{PP} signal level is high ("H"), the chip automatically enters the EPROM mode. Table 1 list the correspondence between pins and Figure 1 and Figure 2 give the pin connections in the EPROM mode. When in the EPROM mode, ports P0, P1, P2, P5₀ to P5₂ and CNV_{SS} are used for the PROM (equivalent to the M5L27256). When in this mode, the built-in PROM can be written to or read from using these pins in the same way as with the M5L27256. The oscillator should be connected to the X_{IN} and X_{OUT} pins, or external clock should be connected to the X_{IN} pin.

Table 1. Pin function in EPROM mode

	M37450E8-XXXSP/FP, M37450E8SS/FS	M5L27256
V _{CC}	V _{CC}	V _{CC}
V _{PP}	CNV _{SS} /V _{PP}	V _{PP}
V _{SS}	V _{SS}	V _{SS}
Address input	Ports P0, P1 ₀ -P1 ₅ , P5 ₀	A ₀ -A ₁₄
Data I/O	Port P2	D ₀ -D ₇
CE	P5 ₂ /DB ₂ /CE	CE
OE	P5 ₁ /DB ₁ /OE	OE

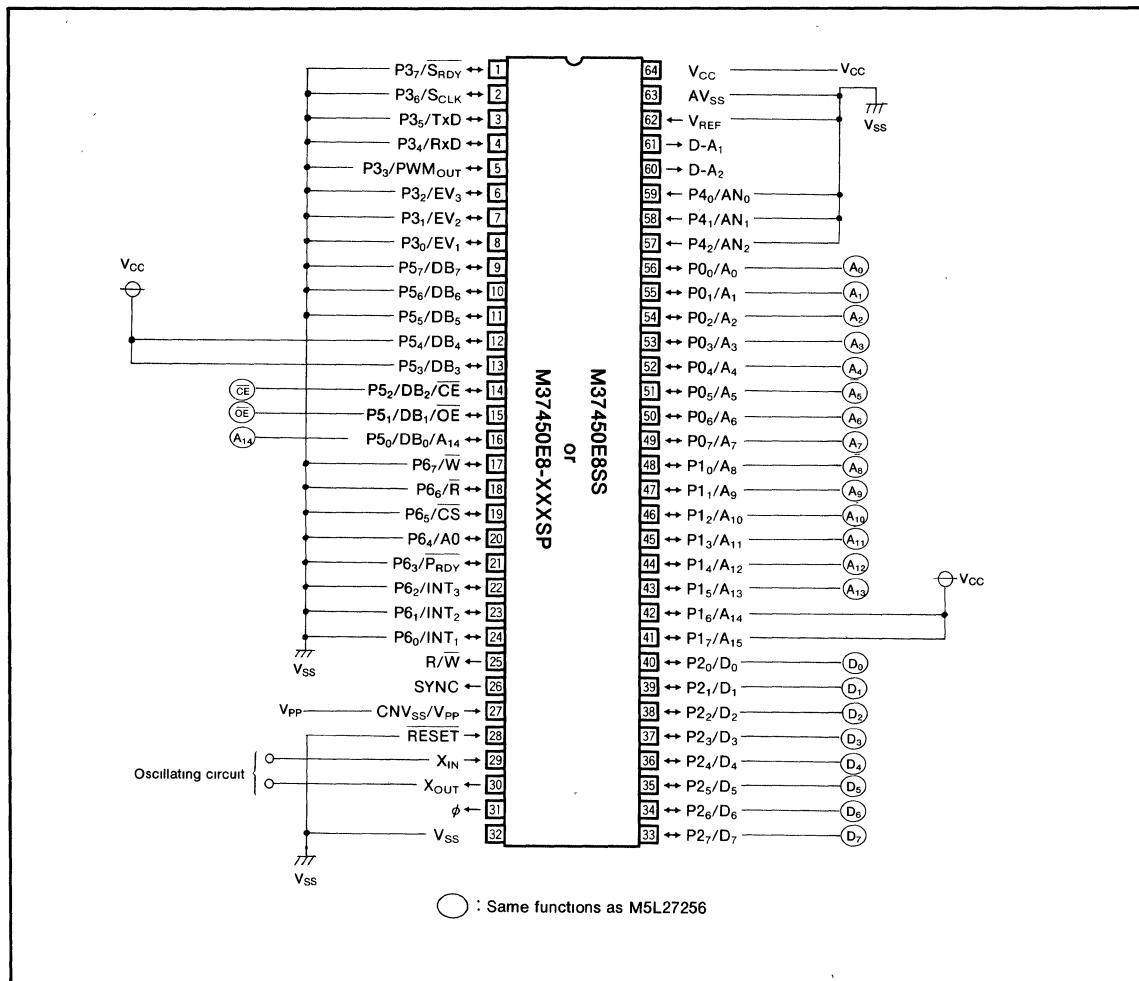


Fig. 1 Pin connection in EPROM mode (64-pin model)

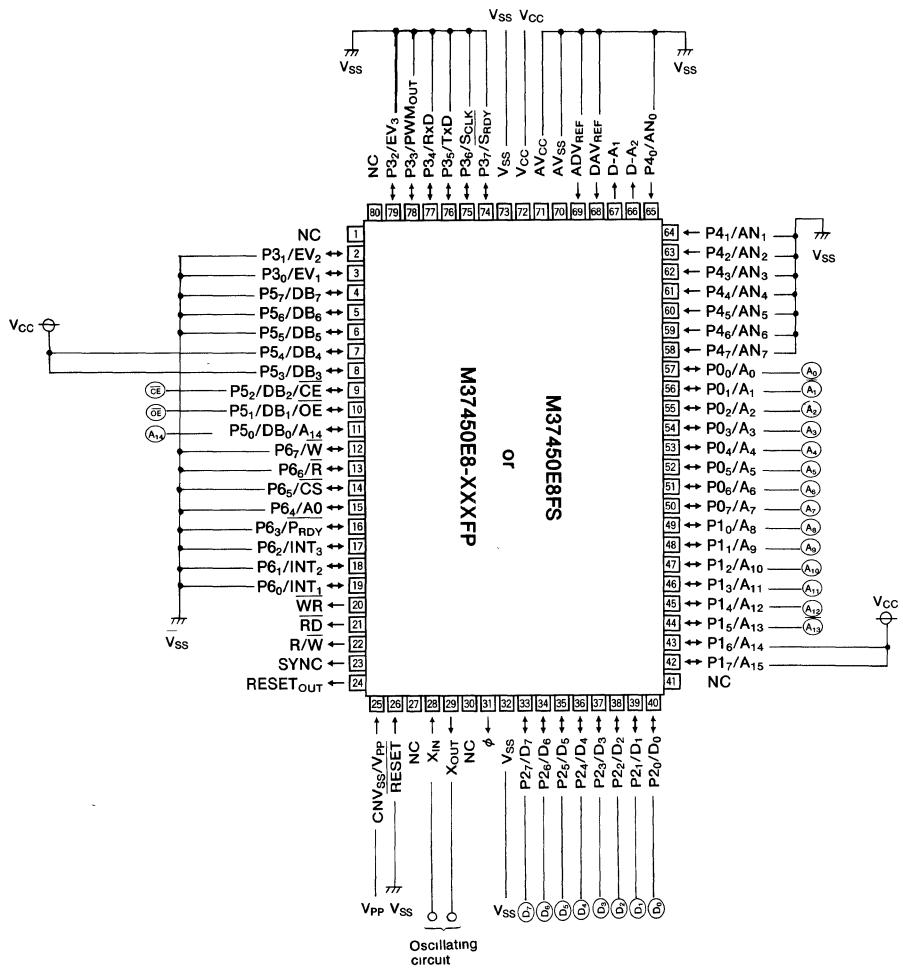


Fig. 2 Pin connection in EPROM mode (80-pin model)

PROM READING, WRITING AND ERASING

Reading

To read the PROM, set the \overline{CE} and \overline{OE} pins to a "L" level, and supply 0V to the \overline{RESET} pin, 5V to the V_{CC} pin and the CNV_{SS} (V_{PP}) pin. Input the address of the data (A_0 to A_{14}) to be read and the data will be output to the I/O pins D_0 to D_7 . The data I/O pins will be floating when the \overline{OE} pin is in the "H" state.

Writing

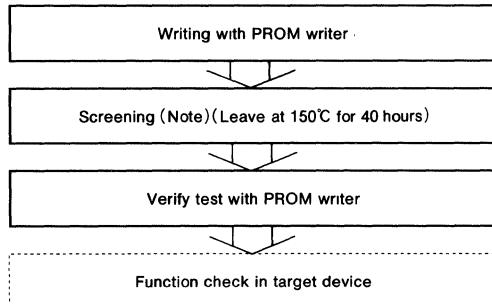
To write to the PROM, set the \overline{OE} pin to a "H" level, and supply 0V to the \overline{RESET} pin, 6V to the V_{CC} pin and 12.5V to the V_{PP} pin. The CPU will enter the program mode when V_{PP} is applied to the V_{PP} pin. The address to be written to is selected with pins A_0 to A_{14} , and the data to be written is input to pins D_0 to D_7 . Set the \overline{CE} pin to a "L" level to begin writing.

Erasing

Data can only be erased on the M37450E8SS/FS ceramic package, which includes a window. To erase data on this chip, use an ultraviolet light source with a 2537 Angstrom wave length. The minimum radiation power necessary for erasing is $15W\cdot s/cm^2$.

NOTES ON HANDLING

- (1) Sunlight and fluorescent light contain wave lengths capable of erasing data. For ceramic package types, cover the transparent window with a seal (provided) when this chip is in use. However, this seal must not contact the lead pins.
- (2) Before erasing, the glass should be cleaned and stains such as finger prints should be removed thoroughly. If these stains are not removed, complete erasure of the data could be prevented.
- (3) Since a high voltage is used to write data, care should be taken when turning on the PROM writer's power.
- (4) For the programmable microcomputer (shipped in blank or OTP type), Mitsubishi does not perform PROM write test and screening in the assembly process and following process. To improve reliability after write, performing write and test according to the flow below before use is recommended.
- (5) In EPROM mode, address A_{15} is set to "H" automatically.



Note : Since the screening temperature is higher than storage temperature, never expose to 150°C exceeding 100 hours.

Table 2. I/O signal in each mode

Mode \ Pin	\overline{CE}	\overline{OE}	V_{PP}	V_{CC}	Port P2
Read-out	V_{IL}	V_{IL}	5V	5V	Output
Output disable	V_{IL}	V_{IH}	5V	5V	Floating
Programming	V_{IL}	V_{IH}	12.5V	6V	Input
Programming verify	V_{IH}	V_{IL}	12.5V	6V	Output
Program disable	V_{IH}	V_{IH}	12.5V	6V	Floating

Note 1 : V_{IL} and V_{IH} indicate a "L" and "H" input voltage, respectively.

2 : An X indicates either V_{IL} or V_{IH} .

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Conditions	Ratings	Unit
V_{CC}	Supply voltage		-0.3 to 7	V
V_I	Input voltage RESET, X_{IN}		-0.3 to 7	V
V_I	Input voltage P0 ₀ -P0 ₇ , P1 ₀ -P1 ₇ , P2 ₀ -P2 ₇ , P3 ₀ -P3 ₇ , P4 ₀ -P4 ₇ , P5 ₀ -P5 ₇ , P6 ₀ -P6 ₇ , ADV _{REF} , DAV _{REF} , V_{REF} , AV _{CC}	With respect to V _{SS} Output transistors are at "OFF" state	-0.3 to $V_{CC}+0.3$	V
	Input voltage CNV _{SS}		-0.3 to 13 (Note 1)	V
	Output voltage P0 ₀ -P0 ₇ , P1 ₀ -P1 ₇ , P2 ₀ -P2 ₇ , P3 ₀ -P3 ₇ , P5 ₀ -P5 ₇ , P6 ₀ -P6 ₇ , X_{OUT} , ϕ , RD, WR, R/W, RESET _{OUT} , SYNC		-0.3 to $V_{CC}+0.3$	V
P_d	Power dissipation	$T_a = 25^\circ\text{C}$	1000 (Note 2)	mW
T_{opr}	Operating temperature		-10 to 70	°C
Tstg	Storage temperature		-40 to 125	°C

Note 1 : In EPROM programming mode, CNV_{SS} is 13.5V.

2 : 500mW for QFP type

RECOMMENDED OPERATING CONDITIONS

($V_{CC}=5\text{V}\pm5\%$, $T_a=-10$ to 70°C unless otherwise noted)

Symbol	Parameter	Limits			Unit
		Min	Typ	Max	
V_{CC}	Supply voltage	4.75	5	5.25	V
V_{SS}	Supply voltage		0		V
V_{IH}	"H" Input voltage RESET, X_{IN} , CNV _{SS} (Note 1)	0.8 V_{CC}		V_{CC}	V
V_{IH}	"H" Input voltage P0 ₀ -P0 ₇ , P1 ₀ -P1 ₇ , P2 ₀ -P2 ₇ , P3 ₀ -P3 ₇ , P4 ₀ -P4 ₇ , P5 ₀ -P5 ₇ , P6 ₀ -P6 ₇ (except Note 1)	2.0		V_{CC}	V
V_{IL}	"L" Input voltage CNV _{SS} (Note 1)	0		0.2 V_{CC}	V
V_{IL}	"L" Input voltage P0 ₀ -P0 ₇ , P1 ₀ -P1 ₇ , P2 ₀ -P2 ₇ , P3 ₀ -P3 ₇ , P4 ₀ -P4 ₇ , P5 ₀ -P5 ₇ , P6 ₀ -P6 ₇ (except Note 1)	0		0.8	V
V_{IL}	"L" Input voltage RESET	0		0.12 V_{CC}	V
V_{IL}	"L" Input voltage X_{IN}	0		0.16 V_{CC}	V
$I_{OL(peak)}$	"L" peak output current P0 ₀ -P0 ₇ , P1 ₀ -P1 ₇ , P2 ₀ -P2 ₇ , P3 ₀ -P3 ₇ , P5 ₀ -P5 ₇ , P6 ₀ -P6 ₇			10	mA
$I_{OL(avg)}$	"L" average output current P0 ₀ -P0 ₇ , P1 ₀ -P1 ₇ , P2 ₀ -P2 ₇ , P3 ₀ -P3 ₇ , P5 ₀ -P5 ₇ , P6 ₀ -P6 ₇ (Note 2)			5	mA
$I_{OH(peak)}$	"H" peak output current P0 ₀ -P0 ₇ , P1 ₀ -P1 ₇ , P2 ₀ -P2 ₇ , P3 ₀ -P3 ₇ , P5 ₀ -P5 ₇ , P6 ₀ -P6 ₇			-10	mA
$I_{OH(avg)}$	"H" average output current P0 ₀ -P0 ₇ , P1 ₀ -P1 ₇ , P2 ₀ -P2 ₇ , P3 ₀ -P3 ₇ , P5 ₀ -P5 ₇ , P6 ₀ -P6 ₇ (Note 2)			-5	mA
f(X_{IN})	Clock oscillating frequency	1		10	MHz

Note 1 : Ports operate as INT₁-INT₃(P6₀-P6₂), EV₁-EV₃(P3₀-P3₂), RXD(P3₄) and S_{CLK}(P3₆)

2 : The average output current $I_{OH(avg)}$ and $I_{OL(avg)}$ are the average value during a 100ms

3 : The total of "L" output current $I_{OL(peak)}$ of port P0, P1 and P2 is less than 40mA

The total of "H" output current $I_{OH(peak)}$ of port P0, P1 and P2 is less than 40mA.

The total of "L" output current $I_{OL(peak)}$ of port P3, P5, P6, R/W, SYNC, RESET_{OUT}, RD, WR and ϕ is less than 40mA

The total of "H" output current $I_{OH(peak)}$ of port P3, P5, P6, R/W, SYNC, RESET_{OUT}, RD, WR and ϕ is less than 40mA

ELECTRICAL CHARACTERISTICS ($V_{CC} = 5V \pm 5\%$, $V_{SS} = 0V$, $T_a = -10$ to $70^\circ C$, $f(X_{IN}) = 10MHz$, unless otherwise noted)

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V_{OH}	"H" output voltage RD, WR, R/W, SYNC, RESET _{OUT} , ϕ	$I_{OH} = -2mA$	$V_{CC} - 1$			V
V_{OH}	"H" output voltage P0 ₀ -P0 ₇ , P1 ₀ -P1 ₇ , P2 ₀ -P2 ₇ , P3 ₀ -P3 ₇ , P5 ₀ -P5 ₇ , P6 ₀ -P6 ₇	$I_{OH} = -5mA$	$V_{CC} - 1$			V
V_{OL}	"L" output voltage P0 ₀ -P0 ₇ , P1 ₀ -P1 ₇ , P2 ₀ -P2 ₇ , P3 ₀ -P3 ₇ , P5 ₀ -P5 ₇ , P6 ₀ -P6 ₇ , RD, WR, R/W, SYNC, RESET _{OUT} , ϕ	$I_{OL} = 2mA$			0.45	V
V_{OL}	"L" output voltage P0 ₀ -P0 ₇ , P1 ₀ -P1 ₇ , P2 ₀ -P2 ₇ , P3 ₀ -P3 ₇ , P5 ₀ -P5 ₇ , P6 ₀ -P6 ₇	$I_{OL} = 5mA$			1	V
$V_{T+} - V_{T-}$	Hysteresis INT ₁ -INT ₃ (P6 ₀ -P6 ₂), EV ₁ -EV ₃ (P3 ₀ -P3 ₂), RxD(P3 ₄), SCLK(P3 ₆)	Function input level	0.3		1	V
$V_{T+} - V_{T-}$	Hysteresis RESET				0.7	V
$V_{T+} - V_{T-}$	Hysteresis X _{IN}			0.1	0.5	V
I_{IL}	"L" input current P0 ₀ -P0 ₇ , P1 ₀ -P1 ₇ , P2 ₀ -P2 ₇ , P3 ₀ -P3 ₇ , P4 ₀ -P4 ₇ , P5 ₀ -P5 ₇ , P6 ₀ -P6 ₇ , RESET, X _{IN}	$V_i = V_{SS}$	-5		5	μA
I_{IH}	"H" input current P0 ₀ -P0 ₇ , P1 ₀ -P1 ₇ , P2 ₀ -P2 ₇ , P3 ₀ -P3 ₇ , P4 ₀ -P4 ₇ , P5 ₀ -P5 ₇ , P6 ₀ -P6 ₇ , RESET, X _{IN}	$V_i = V_{CC}$	-5		5	μA
V_{RAM}	RAM retention voltage	At stop mode	2			V
I_{CC}	Supply current	At system operation $f(X_{IN}) = 10MHz$		6	10	mA
		At stop mode (Note 1)		1	10	μA

Note 1 : The terminals RD, WR, R/W, SYNC, RESET_{OUT}, ϕ , D-A₁ and D-A₂ are all open. The other ports, which are in the input mode, are connected to V_{SS} . A-D converter is in the A-D completion state. The current through ADV_{REF} and DAV_{REF} is not included(Fig 6)

A-D CONVERTER CHARACTERISTICS
 $(V_{CC} = AV_{CC} = 5V, V_{SS} = AV_{SS} = 0V, T_a = 25^\circ C, f(X_{IN}) = 10MHz, \text{unless otherwise noted})$

Symbol	Parameter	Test conditions	Limits			Unit
			Min	Typ	Max	
—	Resolution				8	Bits
—	Absolute accuracy	$V_{CC} = AV_{CC} = ADV_{REF} = 5.12V$		± 1.5	± 3	LSB
t_{CONV}	Conversion time				49	$t_C(\phi)$
V_{IA}	Analog input voltage		AV_{SS}		AV_{CC}	V
V_{ADVREF}	Reference input voltage		2		V_{CC}	V
R_{LADDER}	Ladder resistance value	$ADV_{REF} = 5V$	20	35	50	k Ω
$I_{IADVREF}$	Reference input current	$ADV_{REF} = 5V$	0.1	0.14	0.25	mA
V_{AVCC}	Analog power supply input voltage			V_{CC}		V
V_{AVSS}	Analog power supply input voltage			0		V

D-A CONVERTER CHARACTERISTICS ($V_{CC} = 5V, V_{SS} = AV_{SS} = 0V, T_a = 25^\circ C$, unless otherwise noted)

Symbol	Parameter	Test conditions	Limits			Unit
			Min	Typ	Max	
—	Resolution				8	Bits
—	Absolute accuracy	$V_{CC} = DAV_{REF} = 5.12V$			1.0	%
t_{SU}	Setup time				3	μs
R_o	Output resistance		1	2	4	k Ω
V_{AVSS}	Analog power supply input voltage			0		V
V_{DAVREF}	Reference input voltage		4		V_{CC}	V
I_{DAVREF}	Reference power input current (Each pin)		0	2.5	5	mA

TIMING REQUIREMENTS

Port/single-chip mode ($V_{CC}=5V \pm 5\%$, $V_{SS}=0V$, $T_a=-10$ to $70^\circ C$, unless otherwise noted)

Symbol	Parameter	Test condition	Limits			Unit
			Min.	Typ	Max	
$t_{SU}(P0D-\phi)$	Port P0 input setup time	Fig. 3	200			ns
$t_{SU}(P1D-\phi)$	Port P1 input setup time		200			ns
$t_{SU}(P2D-\phi)$	Port P2 input setup time		200			ns
$t_{SU}(P3D-\phi)$	Port P3 input setup time		200			ns
$t_{SU}(P4D-\phi)$	Port P4 input setup time		200			ns
$t_{SU}(P5D-\phi)$	Port P5 input setup time		200			ns
$t_{SU}(P6D-\phi)$	Port P6 input setup time		200			ns
$t_h(\phi-P0D)$	Port P0 input hold time		40			ns
$t_h(\phi-P1D)$	Port P1 input hold time		40			ns
$t_h(\phi-P2D)$	Port P2 input hold time		40			ns
$t_h(\phi-P3D)$	Port P3 input hold time		40			ns
$t_h(\phi-P4D)$	Port P4 input hold time		40			ns
$t_h(\phi-P5D)$	Port P5 input hold time		40			ns
$t_h(\phi-P6D)$	Port P6 input hold time		40			ns
$t_C(X_{IN})$	External clock input cycle time		100	1000		ns
$t_W(X_{INL})$	External clock input "L" pulse width		30			ns
$t_W(X_{INH})$	External clock input "H" pulse width		30			ns
$t_r(X_{IN})$	External clock rising edge time			20		ns
$t_f(X_{IN})$	External clock falling edge time			20		ns

Master CPU bus interface timing (\overline{R} and \overline{W} separation type mode)

($V_{CC}=5V \pm 5\%$, $V_{SS}=0V$, $T_a=-10$ to $70^\circ C$, unless otherwise noted)

Symbol	Parameter	Test condition	Limits			Unit
			Min.	Typ	Max	
$t_{SU}(CS-\overline{R})$	CS setup time	Fig. 3	0			ns
$t_{SU}(CS-\overline{W})$	CS setup time		0			ns
$t_h(\overline{R}-CS)$	CS hold time		0			ns
$t_h(\overline{W}-CS)$	\overline{CS} hold time		0			ns
$t_{SU}(A-\overline{R})$	A0 setup time		40			ns
$t_{SU}(A-\overline{W})$	A0 setup time		40			ns
$t_h(\overline{R}-A)$	A0 hold time		10			ns
$t_h(\overline{W}-A)$	A0 hold time		10			ns
$t_W(R)$	Read pulse width		160			ns
$t_W(W)$	Write pulse width		160			ns
$t_{SU}(D-\overline{W})$	Date input setup time before write		100			ns
$t_h(\overline{W}-D)$	Date input hold time after write		10			ns

Master CPU bus interface timing (R/ \overline{W} type mode)

($V_{CC}=5V \pm 5\%$, $V_{SS}=0V$, $T_a=-10$ to $70^\circ C$, unless otherwise noted)

Symbol	Parameter	Test condition	Limits			Unit
			Min.	Typ	Max	
$t_{SU}(CS-E)$	\overline{CS} setup time	Fig. 4	0			ns
$t_h(E-CS)$	\overline{CS} hold time		0			ns
$t_{SU}(A-E)$	A0 setup time		40			ns
$t_h(E-A)$	A0 hold time		10			ns
$t_{SU}(RW-E)$	R/W setup time		40			ns
$t_h(E-RW)$	R/W hold time		10			ns
$t_W(E_L)$	Enable clock "L" pulse width		160			ns
$t_W(E_H)$	Enable clock "H" pulse width		160			ns
$t_r(E)$	Enable clock rising edge time			25		ns
$t_f(E)$	Enable clock falling edge time			25		ns
$t_{SU}(D-E)$	Data input setup time before write		100			ns
$t_h(E-D)$	Data input hold time after write		10			ns

MITSUBISHI MICROCOMPUTERS
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M37450E8SS/FS

PROM VERSION of M37450M8-XXXSP/FP

Local bus/memory expansion mode, microprocessor mode

($V_{CC}=5V \pm 5\%$, $V_{SS}=0V$, $T_a=-10$ to $70^\circ C$, unless otherwise noted)

Symbol	Parameter	Test condition	Limits			Unit
			Min.	Typ.	Max.	
$t_{SU}(D-\phi)$	Data input setup time	Fig. 5	130			ns
$t_h(\phi-D)$	Data input hold time		0			ns
$t_{SU}(D-RD)$	Data input setup time		130			ns
$t_h(RD-D)$	Data input hold time		0			ns

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SWITCHING CHARACTERISTICS

Port/single-chip mode ($V_{CC}=5V\pm5\%$, $V_{SS}=0V$, $T_a=-10$ to $70^{\circ}C$, unless otherwise noted)

Symbol	Parameter	Test condition	Limits		Unit
			Min	Typ.	
$t_d(\phi-P0Q)$	Port P0 data output delay time	Fig. 3			200 ns
$t_d(\phi-P1Q)$	Port P1 data output delay time				200 ns
$t_d(\phi-P2Q)$	Port P2 data output delay time				200 ns
$t_d(\phi-P3Q)$	Port P3 data output delay time				200 ns
$t_d(\phi-P5Q)$	Port P5 data output delay time				200 ns
$t_d(\phi-P6Q)$	Port P6 data output delay time				200 ns
$t_C(\phi)$	Cycle time		400		4000 ns
$t_W(\phi_H)$	ϕ clock pulse width ("H" level)		190		ns
$t_W(\phi_L)$	ϕ clock pulse width ("L" level)		170		ns
$t_r(\phi)$	ϕ clock rising edge time				20 ns
$t_f(\phi)$	ϕ clock falling edge time				20 ns

Master CPU bus interface (\overline{R} and \overline{W} separation type mode)

($V_{CC}=5V\pm5\%$, $V_{SS}=0V$, $T_a=-10$ to $70^{\circ}C$, unless otherwise noted)

Symbol	Parameter	Test condition	Limits		Unit
			Min	Typ.	
$t_a(R-D)$	Data output enable time after read	Fig. 4			120 ns
$t_v(R-D)$	Data output disable time after read		10		85 ns
$t_{PLH}(R-PR)$	$PRDY$ output transmission time after read				150 ns
$t_{PLH}(W-PR)$	$PRDY$ output transmission time after write				150 ns

Master CPU bus interface (R/W type mode) ($V_{CC}=5V\pm5\%$, $V_{SS}=0V$, $T_a=-10$ to $70^{\circ}C$, unless otherwise noted)

Symbol	Parameter	Test condition	Limits		Unit
			Min.	Typ.	
$t_a(E-D)$	Data output enable time after read	Fig. 4			120 ns
$t_v(E-D)$	Data output disable time after read		10		85 ns
$t_{PLH}(E-PR)$	$PRDY$ output transmission time after E clock				150 ns

Local bus/memory expansion mode, microprocessor mode

($V_{CC}=5V\pm5\%$, $V_{SS}=0V$, $T_a=-10$ to $70^{\circ}C$, unless otherwise noted)

Symbol	Parameter	Test condition	Limits		Unit
			Min	Typ.	
$t_d(\phi-A)$	address delay time after ϕ	Fig. 5			150 ns
$t_v(\phi-A)$	address effective time after ϕ		10		ns
$t_v(RD-A)$	address effective time after RD		10		ns
$t_v(WR-A)$	address effective time after WR		10		ns
$t_d(\phi-D)$	data output delay time after ϕ				160 ns
$t_d(WR-D)$	data output delay time after WR				160 ns
$t_v(\phi-D)$	data output effective time after ϕ		20		ns
$t_v(WR-D)$	data output effective time after WR		20		ns
$t_d(\phi-RW)$	R/W delay time after ϕ				150 ns
$t_d(\phi-SYNC)$	SYNC delay time after ϕ				150 ns
$t_w(RD)$	RD pulse width		170		ns
$t_w(WR)$	WR pulse width		170		ns

TEST CONDITION

Input voltage level : V_{IH} 2.4V

V_{IL} 0.45V

Output test level : V_{OH} 2.0V

V_{OL} 0.8V

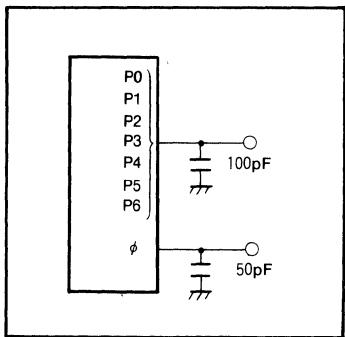


Fig. 3 Test circuit in single-chip mode

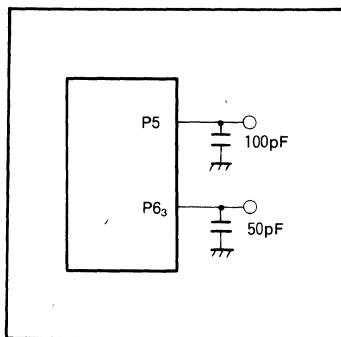


Fig. 4 Master CPU bus interface test circuit

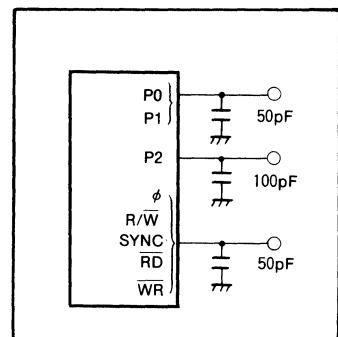


Fig. 5 Local bus test circuit

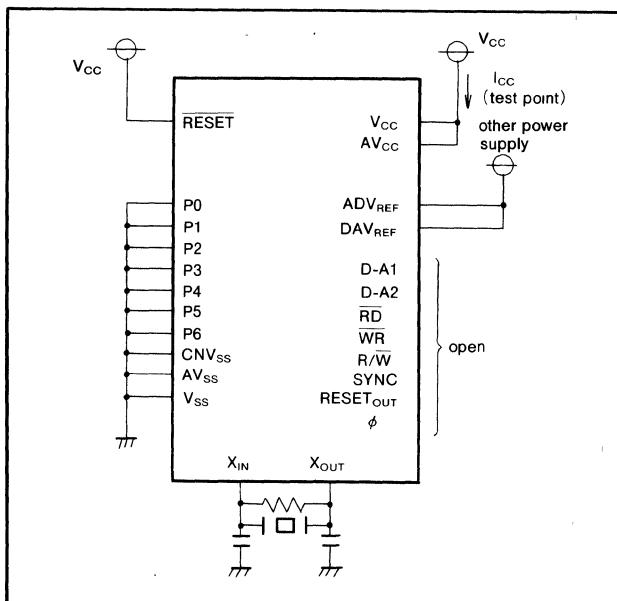
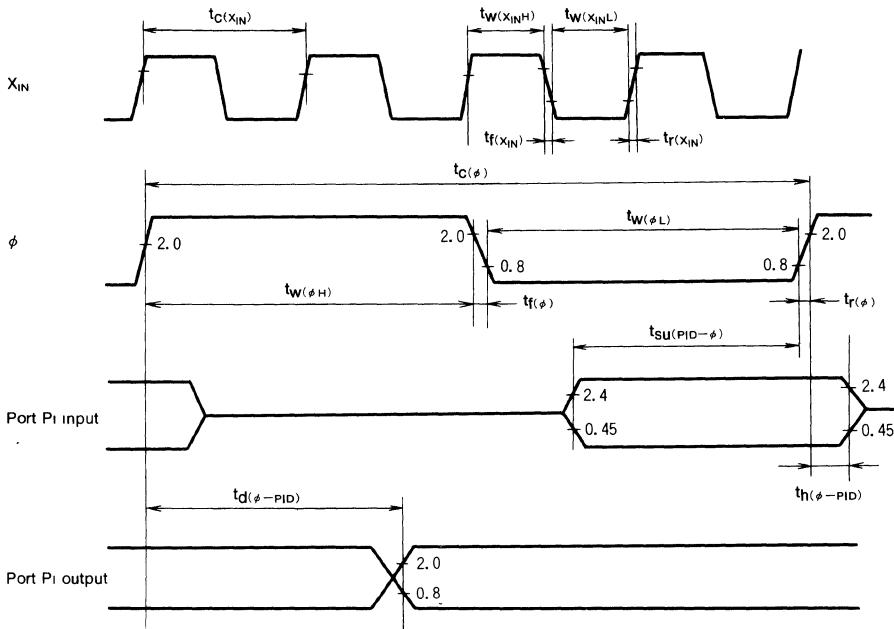


Fig. 6 I_{CC} (at STOP mode) test condition

TIMING DIAGRAM

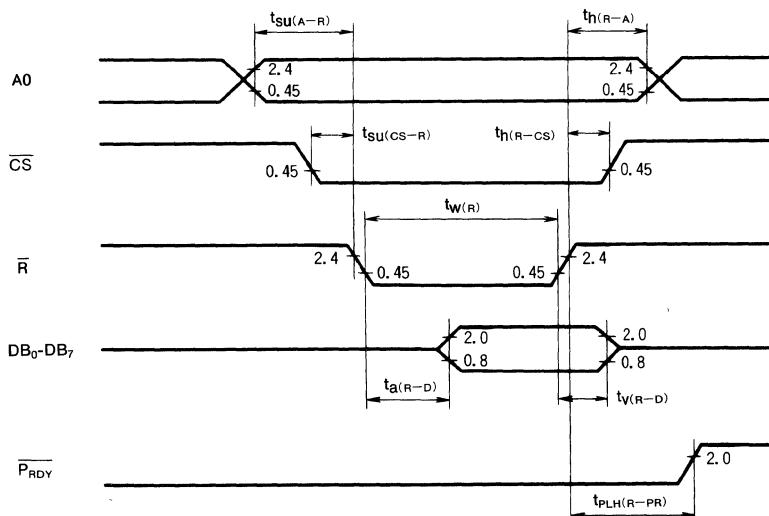
Port/single-chip mode timing diagram



Note : $V_{IH}=0.8V_{CC}$, $V_{IL}=0.16V_{CC}$ of X_{IN}

Master CPU bus interface/ \overline{R} and \overline{W} separation type timing diagram

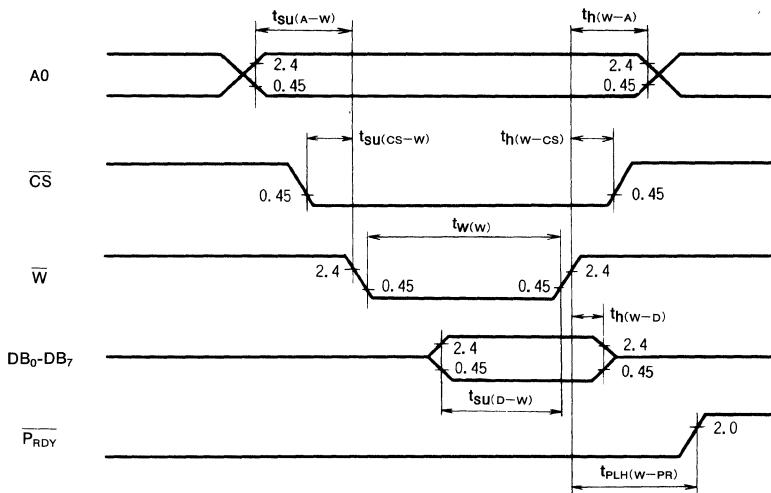
Read



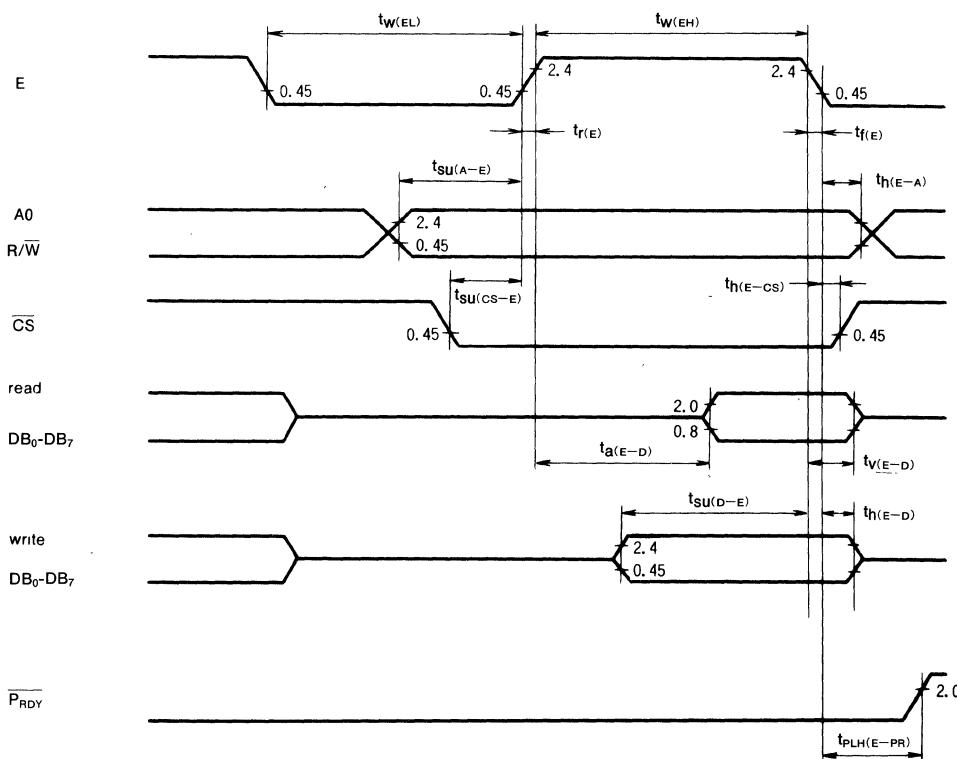
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Write



Master CPU interface/ R/W type timing diagram



Local bus timing diagram

